



PI49FCT3805D

3.3V, 2 x 1:5 CMOS Clock Driver

Features

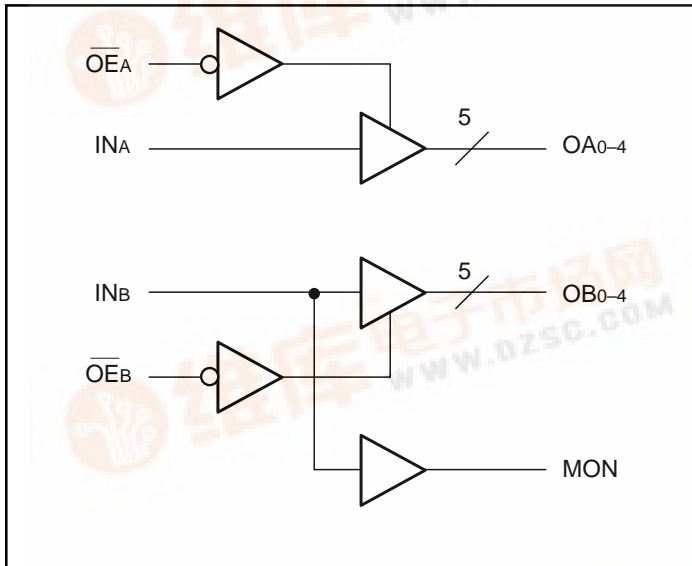
- Low output skew: <270ps
- Switching frequency of 133 MHz
- Fast output rise/fall time: <1.5ns
- Low propagation delay: <3.0ns
- Low input capacitance: <6.0pF
- Balanced CMOS outputs
- Industrial Temperature: -40°C to +85°C
- 3.3V ±10% operation
- Packages available:
 - 20-pin 300-mil wide SOIC (S)
 - 20-pin 150-mil wide QSOP (Q)
 - 20-pin 209-mil wide SSOP (H)

Description

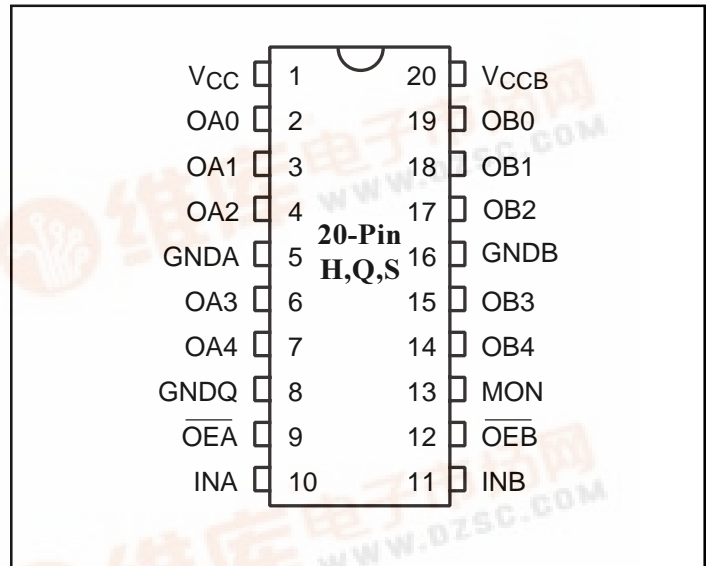
Pericom Semiconductor's PI49FCT series of logic circuits are produced using the Company's advanced submicron CMOS technology to achieve fast speed, low skew, fast slew rate, and low propagation delay for most computing and communication applications.

The PI49FCT3805D is composed of non-inverting drivers. The outputs are configured into 2 groups of one-in, five-out with independent output enable. Group B has an extra MON output. Excellent output signals to power and ground ratio minimize power and ground noise and also improves output performance.

Logic Block Diagram



Pin Configuration



Product Pin Description

Pin Name	Description
$\overline{OE}A, \overline{OE}B$	Hi-Z State Output Enable Inputs (Active LOW)
INA, INB	Clock Inputs
OAN, OBN	Clock Outputs
MON	Monitor Output
GND	Ground
VCC	Power

Truth Table⁽¹⁾

Inputs		Outputs	
$\overline{OE}A, \overline{OE}B$	INA, INB	OAN, OBN	MON
L	L	L	L
L	H	H	H
H	L	Z	L
H	H	Z	H

Note:

1. H = High Voltage Level
L = Low Voltage Level
Z = High Impedance





Capacitance ($T_A = 25^\circ\text{C}$, $f = 1\text{ MHz}$)

Parameters	Description	Test Conditions	Typ	Max.	Units
C_{IN}	Input Capacitance	$V_{IN} = 0V$	3.0	4	pF
C_{OUT}	Output Capacitance	$V_{OUT} = 0V$		6	

Note:

1. This parameter is determined by device characterization but is not production tested.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	-65°C to $+150^\circ\text{C}$
Ambient Temperature with Power Applied	-40°C to $+85^\circ\text{C}$
Supply Voltage to Ground Potential (Inputs & V_{CC} Only)	$-0.5V$ to $+7.0V$
Supply Voltage to Ground Potential (Outputs & I/O Only) ..	$-0.5V$ to $+V_{CC} + 0.5V$
DC Input Voltage	$-0.5V$ to $+4.6V$
DC Output Current	120mA
Power Dissipation	0.5W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Operating Range

Ambient Temperature = -40°C to $+85^\circ\text{C}$, $V_{CC} = 3.3V \pm 0.3V$

DC Electrical Characteristics (Over the Operating Range)

Symbol	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
V_{OH}	Output high voltage $V_{CC} = \text{Min.}$ $V_{IN} = V_{IL}$ or V_{IH}	$I_{OH} = -0.1\text{mA}$ $I_{OH} = -8\text{mA}$ $I_{OH} = -12\text{mA}$	$V_{CC} - 0.2$ 2.4 ⁽³⁾ 2.4 ⁽³⁾	— 3.0 3.0	— — —	V
V_{OL}	Output low voltage $V_{CC} = \text{Min.}$ $V_{IN} = V_{IL}$ or V_{IH}	$I_{OH} = 0.1\text{mA}$ $I_{OH} = 8\text{mA}$ $I_{OH} = 12\text{mA}$	— — —	— 0.2 0.3	0.2 0.4 0.4	
V_{IH}	Input high voltage	LOW logic	2.0	—	5.5	
V_{IL}	Input low voltage	HIGH logic	-0.5	—	0.8	
I_{IH}	Input high current	$V_{CC} = \text{Max.}$, $V_{IN} = V_{CC}$	—	—	1	μA
I_{IL}	Input low current	$V_{CC} = \text{Max.}$, $V_{IN} = \text{GND}$	—	—	-1	
I_{OZH} I_{OZL}	High impedance output current	$V_{CC} = \text{Max.}$, all outputs disabled	$V_{OUT} = V_{CC}$ $V_{OUT} = \text{GND}$	— —	1 -1	
V_{IK}	Clamp diode voltage	$V_{CC} = \text{Min.}$, $I_{IN} = -18\text{mA}$	—	-0.7	-1.2	V
I_{OH}	Output HIGH ⁽⁴⁾ current	$V_{OUT} = 1.5V$, $V_{IN} = V_{IL}$ or V_{IH} , $V_{CC} = 0V$	-45	-74	-180	mA
I_{OL}	Output LOW ⁽⁴⁾ current	$V_{OUT} = 1.5V$, $V_{IN} = V_{IL}$ or V_{IH} , $V_{CC} = 0V$	50	90	200	
I_{OS}	Short circuit ⁽⁵⁾ current	$V_{CC} = \text{Max.}$	-60	-135	-240	

Notes:

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at $V_{CC} = 3.3V$, $+25^\circ\text{C}$ ambient and maximum loading.
3. $V_{OH} = V_{CC} - 0.6V$ at rated current.
4. This parameter is determined by device characterization but is not production tested.
5. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

Power Supply Characteristics

Parameters	Description	Test Conditions ⁽¹⁾		Min.	Typ ⁽²⁾	Max.	Units
I _{CC}	Quiescent Power Supply Current	V _{CC} = Max.	V _{IN} = GND or V _{CC}	—	0.1	30	μA
ΔI _{CC}	Supply Current per Inputs @ TTL HIGH	V _{CC} = Max.	V _{IN} = V _{CC} - 0.6V ⁽³⁾	—	110	300	μA
I _{CCD}	Supply Current per Input per MHz ⁽⁴⁾	V _{CC} = Max., Outputs Open OEA or OEB = GND Per Output Toggling 50% Duty Cycle	V _{IN} = V _{CC} V _{IN} = GND	—	0.09	0.16	mA/ MHz
I _C		V _{CC} = Max., Outputs Open f _O = 10 MHz 50% Duty Cycle OEA or OEB = GND Mon. Outputs Toggling	V _{IN} = V _{CC} V _{IN} = GND	—	1.3	9.0 ⁽⁵⁾	mA
			V _{IN} = V _{CC} - 0.6V V _{IN} = GND	—	1.3	10.0 ⁽⁵⁾	
		V _{CC} = Max., Outputs Open f _O = 2.5 MHz 50% Duty Cycle OEA or OEB = GND Eleven Outputs Toggling	V _{IN} = V _{CC} V _{IN} = GND	—	4.4	6.0 ⁽⁵⁾	
			V _{IN} = V _{CC} - 0.6V V _{IN} = GND	—	4.4	7.0 ⁽⁵⁾	

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- Typical values are at V_{CC} = 3.3V, +25°C ambient.
- Per TTL driven input (V_{IN} = V_{CC} - 0.6V); all other inputs at V_{CC} or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the I_C formula. These limits are guaranteed but not tested.

$$6. I_C = I_{\text{QUIESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$$

$$I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_O N_O)$$

I_{CC} = Quiescent Current

ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = V_{CC} - 0.6V)

D_H = Duty Cycle for TTL Inputs High

N_T = Number of TTL Inputs at D_H

I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

f_O = Output Frequency

N_O = Number of Outputs at f_O

All currents are in milliamps and all frequencies are in megahertz.

Switching Characteristics over Operating Range

Symbol	Description	Condition	Max. ⁽²⁾	Units
t_{PLH} t_{PHL}	Propagation Delay A to Bn	Reference Voltage = 1.5V	3.0	ns
$t_{R/F}$	Rise/Fall Time 0.4V to 2.4V 2.4V to 0.4V	$C_L = 15\text{pF}$ $C_L = 15\text{pF}$	1.5	
$t_{SK(p)}$	Pulse Skew	Reference 1.5V	0.27	
$t_{SK(o)}$	Output Skew	Reference 1.5V	0.27	
$t_{SK(t)}$	Package Skew	Reference 1.5V	0.55	
$t_{ZL}, t_{ZH},$ t_{LZ}, t_{HZ}	Enable/Disable Time		5.2	
F_{MAX}	Input Frequency		133	MHz

Note:

1. Lumped load, $C_L = 15\text{pF}$
2. These parameters are guaranteed by design
3. Series Resistor loading = 33ohms (See Test Circuit)

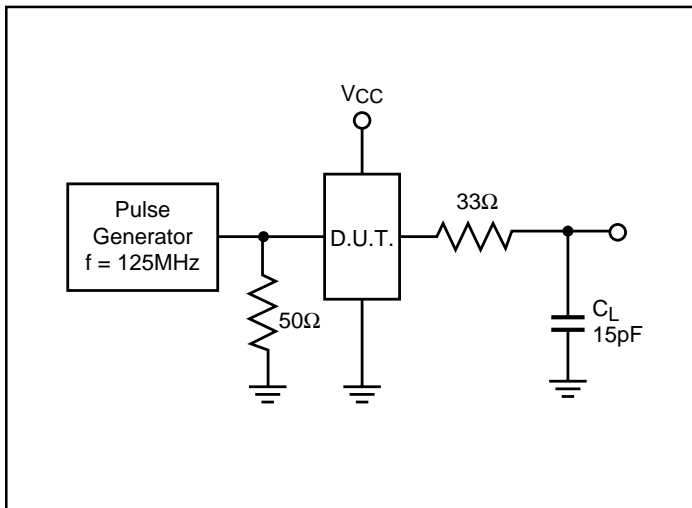
Switch Position

Test	Switch
Disable LOW Enable LOW	6V
Disable HIGH Enable HIGH	GND
All Other Inputs	Open

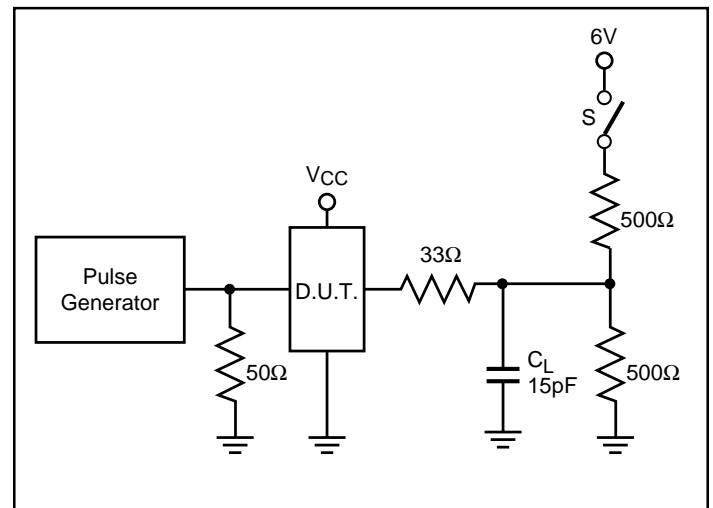
Definitions:

C_L = Load capacitance: includes jig and probe capacitance.
 R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

Tests Circuit for 133 MHz

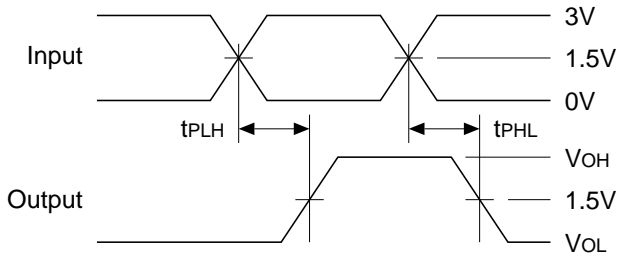


Enable/Disable Time Test Set-Up

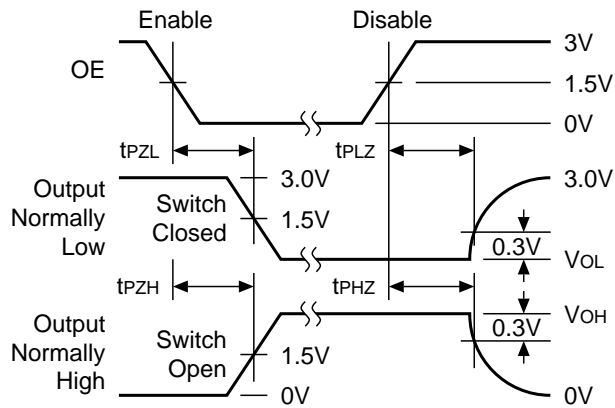


Switching Waveforms

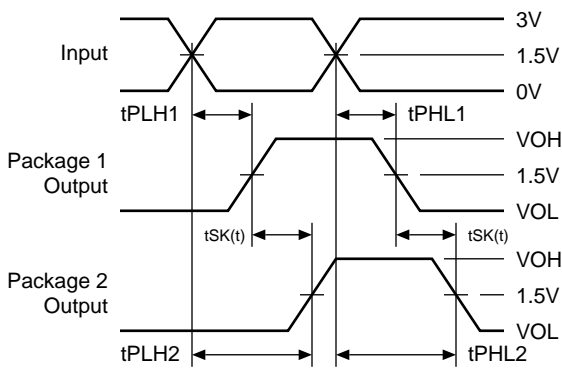
Propagation Delay



Enable and Disable Times

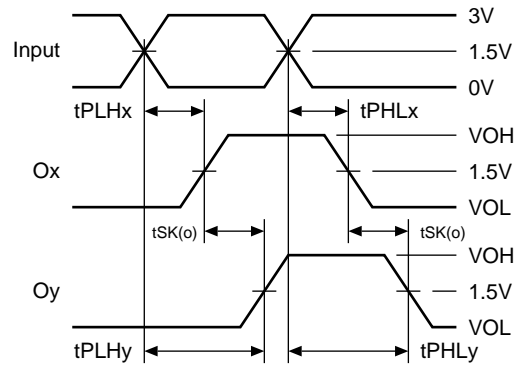


Package Skew – $t_{SK(t)}$



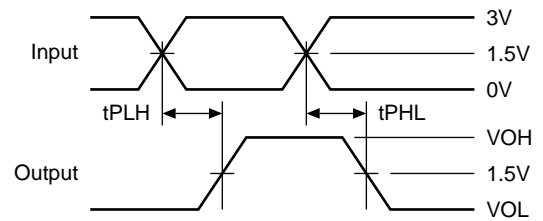
$$t_{SK(t)} = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

Output Skew – $t_{SK(o)}$



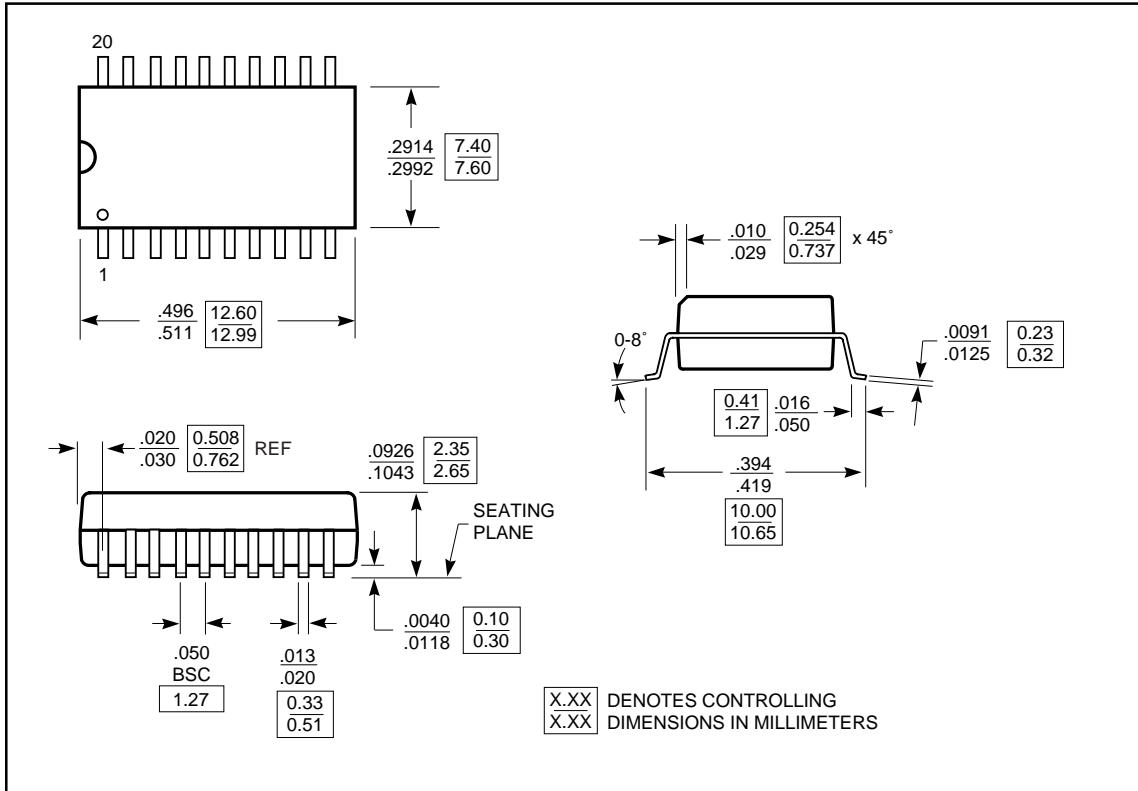
$$t_{SK(o)} = |t_{PLHy} - t_{PLHx}| \text{ or } |t_{PHLy} - t_{PHLx}|$$

Pulse Skew – $t_{SK(p)}$

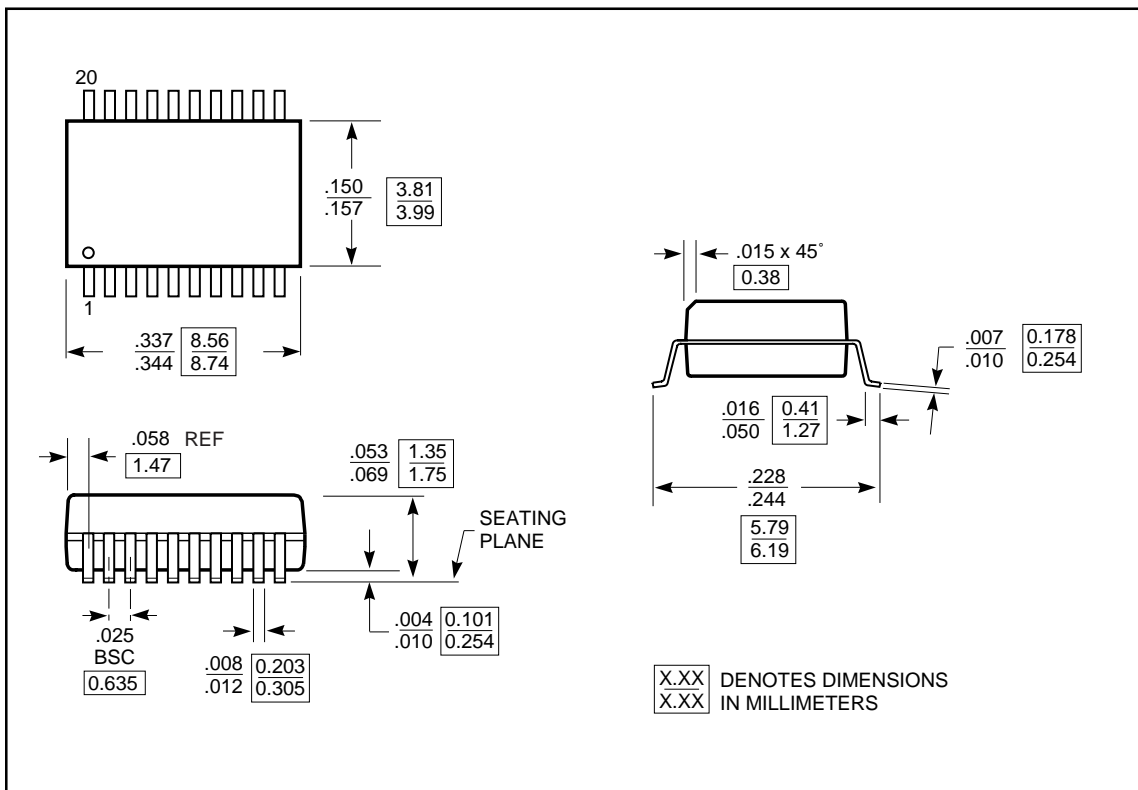


$$t_{SK(p)} = |t_{PHL} - t_{PLH}|$$

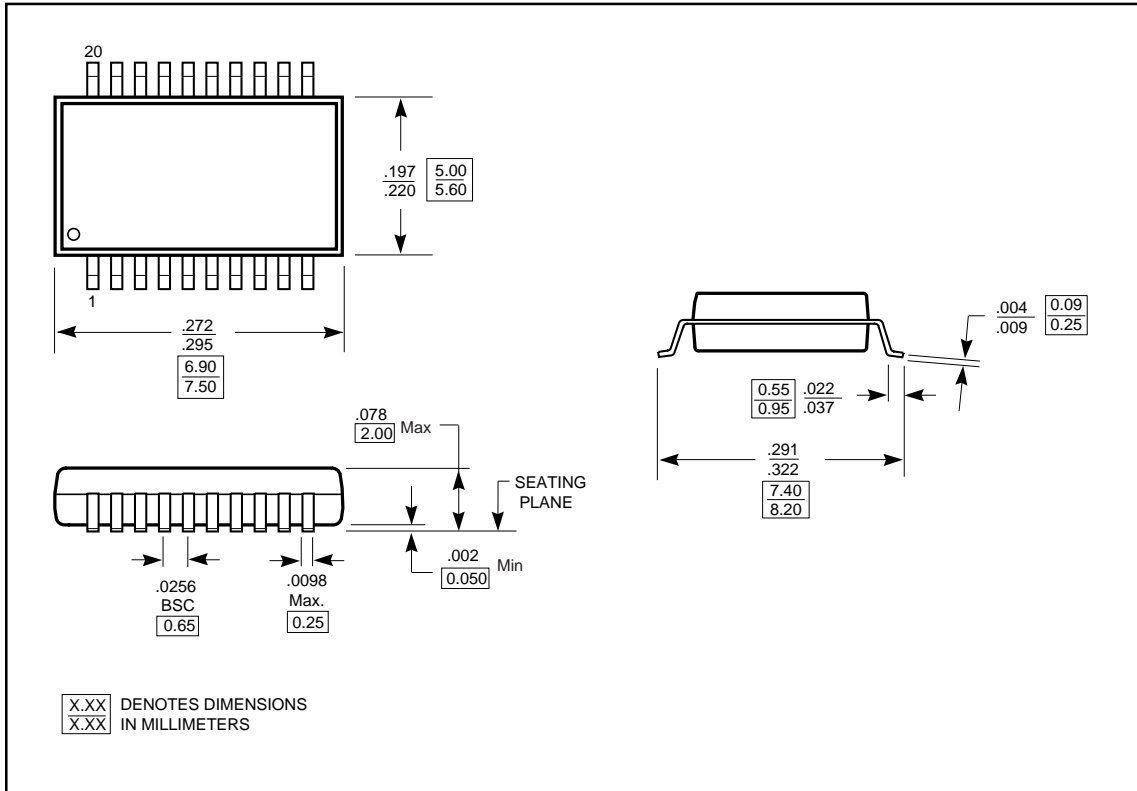
20-Pin 300-milwide SOIC (S)



20-Pin 150-milwide QSOP (Q)



20-Pin 209-mil wide SSOP (H)



Ordering Information

Ordering Code	Part Marking	Package Type	Rating
PI49FCT3805DH	PI49FCT3805HD	20-pin 209 mil SSOP	Industrial
PI49FCT3805DQ	PI49FCT3805QD	20-pin 150 mil QSOP	
PI49FCT3805DS	PI49FCT3805SD	20-pin 300 mil SSIC	